566.38683CX1

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

X. Coff

Applicants:

YOSHIDA, et al

Serial No.:

Rule 1.53(b) continuation of U.S. Patent

Application Serial No. 09/581,814, filed June

19, 2000

Filed:

Herewith

For:

ľij.

ΥLI

ABRASIVE METHOD OF POLISHING TARGET MEMBER AND

PROCESS FOR PRODUCING SEMICONDUCTOR DEVICE

Group of parent:

3723

Examiner of parent: D. Nguyen

PRELIMINARY AMENDMENT

Assistant Commissioner of Patents

January 11, 2002

Washington, D.C. 20231

Sir:

Please amend the above-identified application, prior to examination thereof, as follows:

## IN THE SPECIFICATION

Please amend the specification as follows:

Page 1, before line 1 "TECHNICAL FIELD", insert the following:

## -- CROSS REFERENCE TO RELATED APPLICATIONS

This application is a Continuation Application of Application Serial No. 09/581,814, filed June 19, 2000.--